NSN 5961-01-084-5827

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View Online at https://aerobasegroup.com/nsn/5961-01-084-5827 **Inclosure Material:** Glass and metal **Overall Length:** Between 0.275 inches and 0.285 inches Overall Diameter: Between 0.175 inches and 0.200 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 collector to base voltage/static/emitter open and 25.0 collector to emitter voltage/static/base open and 3.5 emitter to base voltage, static, collector open **Power Rating Per Characteristic:** 16.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Terminal surface gold **Precious Material:** Gold **Thread Series Designator: Terminal Type And Quantity:** 4 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Fiig: A110a0

No